# VS-FC420SA15

Vishay Semiconductors



SOT-227 Power Module Single Switch - Power MOSFET, 400 A



PRIMARY CHARACTERISTICS				
V <sub>DSS</sub> 150 V				
R <sub>DS(on)</sub> at 200 A	1.93 mΩ			
Ι <sub>D</sub>	300 A at 90 °C			
Туре	Modules - MOSFET			
Package	SOT-227			

### FEATURES

- I<sub>D</sub> = 400 A, T<sub>C</sub> = 25 °C
- ThunderFET Power MOSFET
- Excellent gate charge x R<sub>DS(on)</sub> product (FOM)
- Reduced switching and conduction losses
- Ultra low gate charge (Qg)
- Maximum 175 °C junction temperature
- UL approved file E78996
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **APPLICATIONS**

- DC/DC conversions
- Motor drives
- DC/AC inverter
- Power supplies
- Uninterruptible power supplies
- AC/DC switch-mode power supplies

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS		
MOSFET						
Drain to source voltage	V <sub>DSS</sub>		150	V		
Continuous dusin surrent V 10.V	1	T <sub>C</sub> = 25 °C	400			
Continuous drain current, $V_{GS at}$ 10 V	ID	T <sub>C</sub> = 90 °C	300	А		
Pulsed drain current	I <sub>DM</sub> <sup>(1)</sup>		860			
Power dissipation	PD	$T_{\rm C} = 25 \ ^{\circ}{\rm C}$	909	W		
Gate to source voltage	V <sub>GS</sub>		± 20	V		
Single pulse avalanche current	E <sub>AS</sub>		720	J		
Avalanche current	I <sub>AS</sub>	$T_{C} = 25 \text{ °C}, L = 10 \text{ mH}, V_{GS} = 10 \text{ V}$	120	А		
MODULE						
Operating junction temperature range	TJ		-55 to +175	- °C		
Operating storage temperature range	T <sub>Stg</sub>		-40 to +150			
Insulation voltage (RMS)	VISOL	any terminal to case, t = 1 min	2500	V		

#### Note

<sup>(1)</sup> Limited at max. junction temperature

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COMPLIANT



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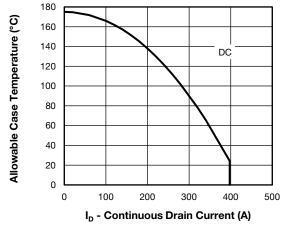
THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Operating junction temperature range		TJ		-55	-	175	°C
Operating storage temperature range		T <sub>Stg</sub>		-40	-	150	U
Junction to case	MOSFET	R <sub>thJC</sub>		-	-	0.165	°C/W
Case to heatsink	Module	R <sub>thCS</sub>	Flat, greased surface	-	0.1	-	C/W
Weight				-	30	-	g
Mounting torque			Torque to terminal	-	-	1.1 (9.7)	Nm (lbf. in)
			Torque to heatsink	-	-	1.3 (11.5)	Nm (lbf. in)
Case style					SOT-227		

ELECTRICAL CHARACTERISTICS (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0 \text{ V}, \text{ I}_{D} = 500 \mu\text{A}$	150	-	-	V
Breakdown voltage temperature coefficient	$\Delta V_{(BR)DSS} / \Delta T_J$	Reference to 25 °C, $I_D = 1.0$ mA	-	9.0	-	mV/°C
Static drain to source on-resistance	R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 200 \text{ A}$	-	1.93	2.75	mΩ
Gate threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 1.0 \text{ mA}$	1.80	3.46	5.4	V
Temperature coefficient of threshold voltage	$\Delta V_{GE(th)} / \Delta T_J$	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 1.0 mA (25 °C to 125 °C)	-	9.6	-	mV/°C
Forward transconductance	g <sub>fs</sub>	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 100 \text{ A}, \text{ V}_{GS} = 10 \text{ V}$	-	200	-	S
Drain to source leakage current	I <sub>DSS</sub>	$V_{DS} = 150 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	-	0.5	10.0	μA
		$V_{DS}$ = 150 V, $V_{GS}$ = 0 V, $T_{J}$ = 150 °C	-	19	-	
Gate to source leakage	I <sub>GSS</sub>	$V_{GS} = \pm 20 V$	-	-	± 200	nA
Total gate charge	Qg	I <sub>D</sub> = 250 A	-	250	-	
Gate to source charge	Q <sub>gs</sub>	$V_{DS} = 75 V$	-	79	-	nC
Gate to drain ("Miller") charge	Q <sub>gd</sub>	V <sub>GS</sub> = 10 V	-	82	-	
Turn-on delay time	$\begin{array}{c c} t_{d(on)} & V_{DD} = 75 \text{ V} \\ \hline t_r & I_D = 100 \text{ A} \\ \hline t_{d(off)} & R_g = 1 \Omega \end{array}$		-	139	-	
Rise time			-	285	-	
Turn-off delay time			-	120	-	ns
Fall time	t <sub>f</sub>	$V_{GS} = 10 V$		142	-	
Input capacitance	$\begin{tabular}{c c c c c c } \hline C_{iss} & V_{GS} = 0 \ V \\ \hline C_{oss} & V_{DS} = 25 \ V \\ \hline C_{rss} & f = 1 \ MHz \end{tabular}$		-	13.7	-	
Output capacitance			-	2.2	-	nF
Reverse transfer capacitance			-	0.104	-	

SOURCE-DRAIN RATINGS AND CHARACTERISTICS (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Continuous source current (body diode)	I <sub>S</sub>		-	-	476	
Pulsed source current (body diode)	I <sub>SM</sub>	MOSFET symbol showing the integral reverse p-n junction diode	-	-	850	A
Diode forward voltage	V <sub>SD</sub>	$I_{\rm S} = 250$ A, $V_{\rm GS} = 0$ V	-	0.95	-	V
Reverse recovery time	t <sub>rr</sub>		-	171	-	ns
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C, I <sub>F</sub> = I <sub>S</sub> = 50 A, dl/dt = 100 A/µs, V <sub>B</sub> = 50 V	-	1032	-	nC
Reverse recovery current	I <sub>RM</sub>			-	А	

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Fig. 1 - Maximum Continuous Drain Current vs. Case Temperature

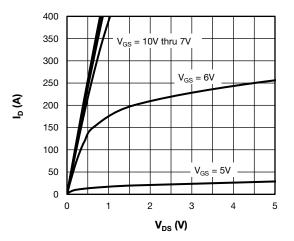


Fig. 2 - Typical Drain to Source Current Output Characteristics at  $T_J$  = 25  $^\circ C$ 

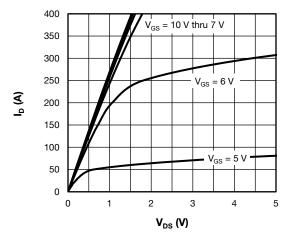


Fig. 3 - Typical Drain to Source Current Output Characteristics at  $T_J$  = 125  $^\circ\text{C}$ 

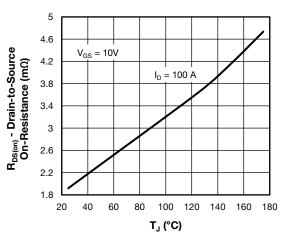


Fig. 4 - Typical Drain-to-Source On-Resistance vs. Temperature

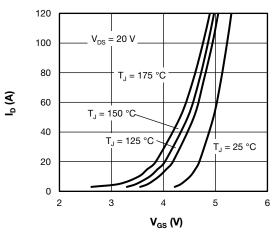


Fig. 5 - Typical Transfer Characteristics

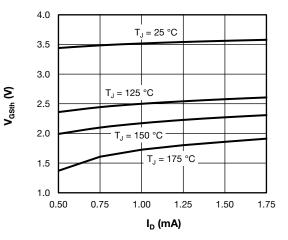


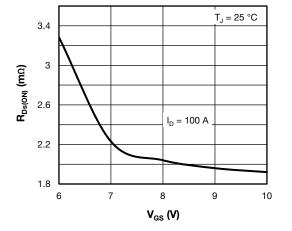
Fig. 6 - Typical Gate Threshold Voltage Characteristics

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Fig. 7 - Typical Drain - State Resistance vs. Gate to Source Voltage

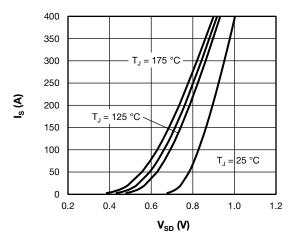


Fig. 8 - Typical Body Diode Source-to-Drain Current Characteristics

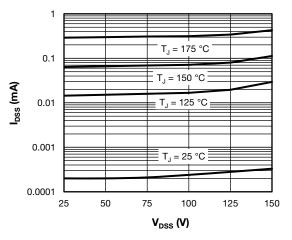


Fig. 9 - Typical Zero Gate Voltage Drain Current

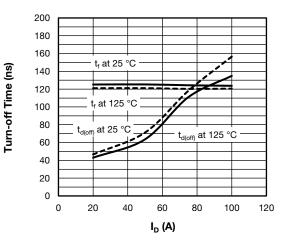
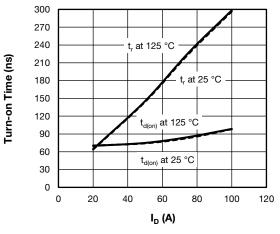


Fig. 10 - Typical Turn-off Switching Time vs.  $\mathrm{I}_\mathrm{D}$ 





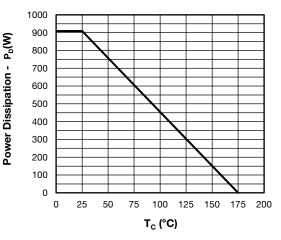


Fig. 12 - Power Dissipation Curve

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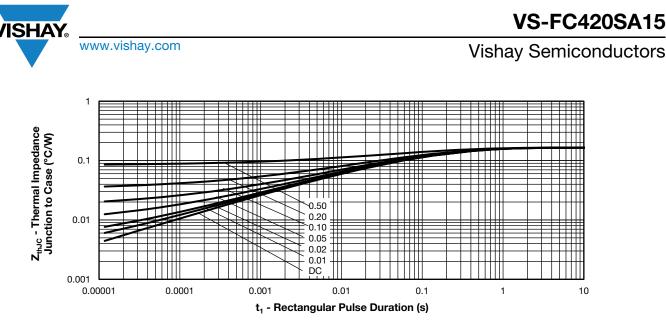


Fig. 13 - Maximum Thermal Impedance Junction-to-Case Characteristics

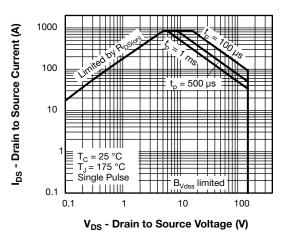


Fig. 14 - Safe Operating Area

### **ORDERING INFORMATION TABLE**

**Device code** vs-F С 420 S Α 15 2 3 (6) (7)1 (4 5 Vishay Semiconductors product 1 2 MOSFET module MOSFET die generation 3 4 Current rating (420 = 420 A) 5 Circuit configuration (S = single switch)

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- Package indicator (SOT-227)
- **7** Voltage rating (15 = 150 V)



CIRCUIT CONFIGURATION				
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING		
Single switch	ß	(3)		

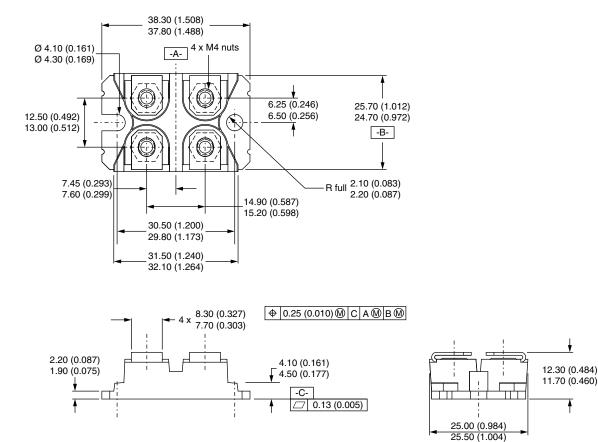


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### **DIMENSIONS** in millimeters





SOT-227 Generation 2

#### **DIMENSIONS** in millimeters (inches)



#### Note

• Controlling dimension: millimeter



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